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NSVMMBT5088LT3G

onsemi

Bipolar Transistors - BJT SS SOT23 LN XSTR NPN 35V

Any questions, please feel free to contact us. info@kaimte.com

Low Noise Transistors

NPN Silicon

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MMBT5088L MMBT5089L	V _{CEO}	30 25	Vdc
Collector-Base Voltage MMBT5088L MMBT5089L	V _{CBO}	35 30	Vdc
Emitter-Base Voltage	V _{EBO}	4.5	Vdc
Collector Current – Continuous	Ι _C	50	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T _A = 25°C Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

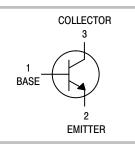


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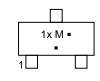
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SOT-23 (TO-236) CASE 318 STYLE 6



MARKING DIAGRAM



1x = Device Code x = Q for MMBT5088L SMMBT5088L x = R for MMBT5089L SMMBT5089L

M = Date Code*

= Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]			
MMBT5088LT1G, SMMBT5088LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel			
NSVMMBT5088LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel			
MMBT5089LT1G, SMMBT5089LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel			

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MMBT5088L MMBT5089L	V _{(BR)CEO}	30 25		Vdc
Collector – Base Breakdown Voltage ($I_C = 100 \ \mu Adc, I_E = 0$)	MMBT5088L MMBT5089L	V _{(BR)CBO}	35 30		Vdc
Collector Cutoff Current $(V_{CB} = 20 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 15 \text{ Vdc}, I_E = 0)$	MMBT5088L MMBT5089L	I _{CBO}	-	50 50	nAdc
Emitter Cutoff Current $(V_{EB(off)} = 3.0 \text{ Vdc}, I_C = 0)$ $(V_{EB(off)} = 4.5 \text{ Vdc}, I_C = 0)$	MMBT5088L MMBT5089L	I _{EBO}		50 100	nAdc
ON CHARACTERISTICS		•		•	•
DC Current Gain (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc)	MMBT5088L MMBT5089L	h _{FE}	300 400	900 1200	-
$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT5088L MMBT5089L		350 450		
$(I_{C} = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MMBT5088L MMBT5089L		300 400		
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$)		V _{CE(sat)}	_	0.5	Vdc
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$		V _{BE(sat)}	_	0.8	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product ($I_C = 500 \ \mu Adc$, $V_{CE} = 5.0 \ Vdc$, f = 20 MHz)		f _T	50	-	MHz
Collector–Base Capacitance (V_{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz emitter guarded)		C _{cb}	-	4.0	pF
Emitter–Base Capacitance (V_{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz collector guarded)		C _{eb}	_	10	pF
Small Signal Current Gain (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, f = 1.0 kHz)	MMBT5088L MMBT5089L	h _{fe}	350 450	1400 1800	_
Noise Figure (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 10 kΩ, f = 1.0 kHz)	MMBT5088L MMBT5089L	NF	-	3.0 2.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

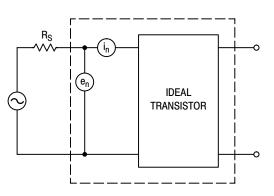


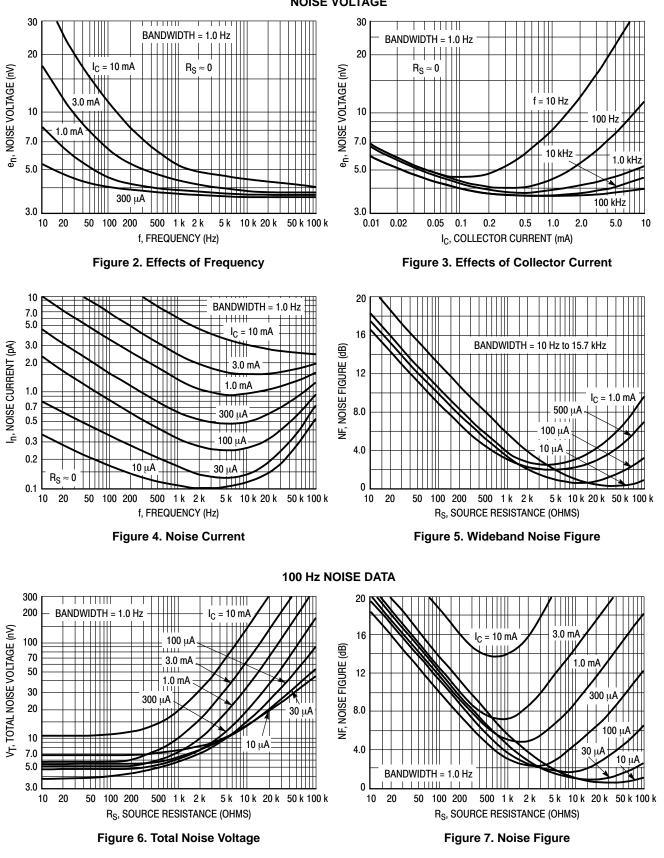
Figure 1. Transistor Noise Model

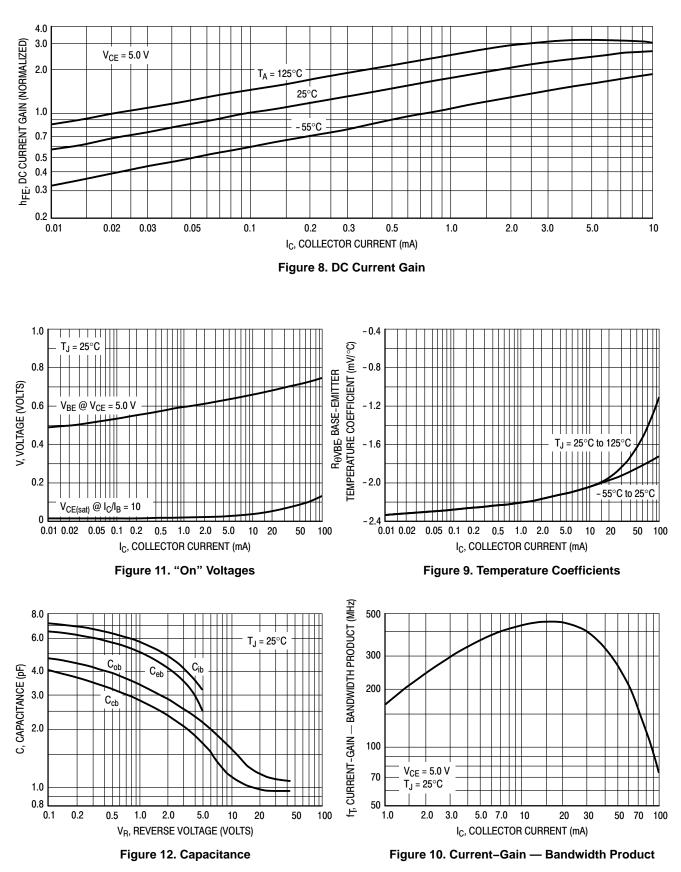
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NOISE CHARACTERISTICS

 $(V_{CE}=5.0~Vdc,~T_{A}=25^{\circ}C)$

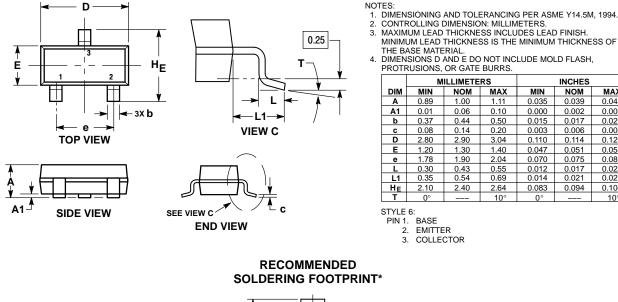
NOISE VOLTAGE

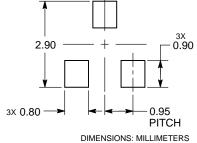




PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR**





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MMBT5088LT1/D

INCHES

NOM

0.039

0.002

0.017

0.006

0.114

0.051

0.075

0.017

0.021

0.094

MAX

1.11

0.10

0.50

0.20

3.04

1.40

2.04 0.55

0.69

2.64

10

MIN

0.035

0.000

0.015

0.003

0.110

0.047

0.070

0.012

0.014

0.083

MAX 0.044

0.004

0.020

0.008

0.120

0.055

0.080

0.027

0.104

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